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A C_6 -DPA/PMMA binary blend ink for high-performance inkjet-printed organic field-effect transistors†

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A solution-processed small-molecule/insulator binary blend offers an optimized blending system for inkjet-printing technology. Due to the spontaneous vertical phase separation, a small-molecule OSC thin-film could be deposited with good crystallization and preferred orientation. However, the uniformity of the semiconducting thin-film is still a critical issue, and the intrinsic properties of the blend ink used in inkjet printing, especially ink stability, are rarely reported. In this paper, a blend system of 2,6-bis(4 hexylphenyl)anthracene (C₆-DPA) and polymethyl methacrylate (PMMA) is used to prepare a highperformance and stabilized electronic ink. Based on this ink, the highest mobility of inkjet-printed organic field-effect transistors is up to 2.01 cm² V⁻¹ s⁻¹ with bottom-gate and top-contact structures. **PAPER**
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Introduction

Printed organic field-effect transistors (OFETs) have been extensively investigated because of their low-cost and large-area printing process, mechanical flexibility, and compatibility with industrial production.1–4 Among different printing technologies, inkjetprinting is attractive because the ink can be deposited on demand directly onto any substrate without a mask or additional etching processes.5–8 Small-molecule organic semiconductors (OSCs) are popular active materials in inkjet-printed OFETs due to their high mobility and good solubility in organic solvents.⁹⁻¹² However, the formation of continuous small-molecule OSC films via inkjet printing is challenging due to the molecular shape, packing anisotropies and ink dewetting.¹³ Blending small-molecule OSCs with insulating polymers has been demonstrated as an effective route for improving the film uniformity and performance of OFETs.14–17 Vertical phase separation occurs spontaneously in the blend due to Marangoni-like instability during solvent evaporation. Semiconductors typically enrich at the upper or lower interface of the film and facilitate the formation of a

uniform and continuous crystalline film, which provides an effective way for charge transport.¹⁸ The use of a small-molecule OSC/polymer blend system to prepare inkjet-printed OFETs has also been investigated.^{19–22} Cho et al. reported the vertical phase-separation in an inkjet-printed 6,13-bis(triisopropylsilylethynyl)pentacene (TIPS-PEN)/amorphous polycarbonate (APC) blend film, where the improvement in the hole mobilities of OFETs was attributed to the movement of the TIPS-PEN molecules toward the air/film interface.¹⁹ Jiang *et al.* optimized the performance of inkjet-printed OFETs and constructed a highgain, fully inkjet-printed Schottky barrier organic thin-film transistor amplifier circuit by adopting a dioctylbenzothienobenzothiophene $(C_8$ -BTBT)/PMMA blend. The transistor signal amplification efficiency was 38.2 S A^{-1} with an ultralow power consumption of $\langle 1 \text{ nW} \rangle^{22}$ Although high performance of the above OFET devices is realized, the uniformity of the OSC thin film is still a critical issue, mainly due to the homogeneous nucleation of the small-molecule OSCs on the substrate.²³⁻²⁶

Here, we report a stabilized organic semiconducting electronic ink for inkjet-printed high-performance OFETs. The smallmolecule semiconductor 2,6-bis(4-hexylphenyl) anthracene $(C_6$ -DPA) is chosen due to its high mobility, high solubility in various organic solvents, commercial availability, as well as good air stability. $27-35$ And polymethyl methacrylate (PMMA) is chosen for our binary blend ink system because of its excellent chemical stability, mechanical properties, easy processing ability and transparency.^{29,36,37} We begin by systematically investigating the effect of solvents, ink concentrations and different blend ratios on the ink stability and microstructure of printed thin films. The structural and electrical properties of the blend films

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in OFETs are further studied. The maximum field-effect mobility of 2.01 cm² V^{-1} s⁻¹ is obtained when the ink was under its optimal conditions, which is comparable to the values reported in single crystal devices.

Results and discussion

For drop-on-demand (DOD) inkjet printing, the rheological properties of the ink, especially the surface tension (y) and viscosity (η) , must be strictly controlled to make sure that the ink can be printed accurately. $38-40$ The ink printability can be described using the inverse Ohnesorge (Oh) number (Z), which is defined as:

$$
Z = \frac{1}{\text{Oh}} = \frac{\eta}{\sqrt{\gamma \rho d}} \tag{1}
$$

where ρ is the ink density, d is the nozzle radius, η is the ink viscosity, and γ is the surface tension of the ink. It has been shown that Z should be within an appropriate range of $1 < Z <$ 10 for an ink to be printable. A low Z value $(Z < 1)$ prevents droplet separation from nozzle, while high Z value $(Z > 10)$ results in the emission of a large number of satellite drops.^{39,40} The surface tension and viscosity of the blend ink can be controlled by varying the solvent, molecular weight (M_w) of the polymer, its concentration and blend ratio (Fig. 1). The surface tension of the ink is nearly consistent with that of a pure solvent regardless of its concentration, while the ink viscosity is proportional to its concentration, the blend ratio and molecular weight of the polymer. In particular, the viscosity curve exhibits non-linearity at high ink concentration due to the nullification of the assumption that there is no interaction

Fig. 1 (a) Surface tension of the ink with different solvents or concentrations. The surface tension of the ink is basically independent of its concentration, but closely related to the type of pure solvent. (b) Ink viscosity with different molecular masses of PMMA or concentrations. (c) Surface tension and viscosity of the ink with different blend ratios. Here, the ink concentration is 4 mg mL $^{-1}$, TCB is used as a solvent, and the molecular weight of PMMA is 550 000.

between macromolecules in the ink. As shown in Fig. 1a, the surface tension of 1,2,4-trichlorobenzene (TCB) is 39.9 mN m^{-1} , which is within the optimum surface tension range for inkjetprinting. Moreover, as shown in Fig. S1 (ESI†), the wettability of TCB can ensure layered growth of OSCs and formation of a large and uniform film. The boiling point of TCB is 221 \degree C, therefore appropriate annealing temperature can be selected over a wide temperature range to reduce the evaporation rate, which will reduce the generation of the coffee ring effect and improve the uniformity of the film. 41 The physical properties of different solvents are summarized in Table S1 (ESI†). TCB is considered the optimal solvent due to its high-boiling point and excellent wettability. In combination with Fig. 1b and c, PMMA with a M_w of 550 000 is selected due to its large molecular weight to provide sufficient vertical phase separation and suitable viscosity. 27 By calculating the Z value, the optimal ratio of the blend system is further determined. As recorded in Table S2 (ESI†), the optimal ratio range of the C_6 -DPA ink for inkjet printing should be less than 75 wt%. Puper

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In order to further confirm the optimal ink conditions and obtain the optimal thin film morphology for OFET devices, we prepared the blend inks under different conditions. Polarized optical microscopy (POM) images showed a strong dependence of the film morphology on the solvents, the ink concentration, and blend ratio (Fig. S2, ESI†). As a result, highly crystalline films can be prepared in blended inks with TCB as the solvent and an ink concentration of 4 mg mL^{-1} . When the microstructure of the film was investigated by atomic force microscopy, it was noticed that when the mixing ratio of C_6 -DPA/PMMA was 2 : 1, the morphology of the film was more uniform, and the root mean square roughness was only 0.948 nm (Fig. 2a–d and Fig. S3, ESI†). These results show that the vertical phase separation of the films is the best at this mixing ratio. For small molecule and polymer blend systems, during the solvent evaporation process, due to the different adhesion of dissolved components to the substrate, the interaction between the solute and the substrate induces vertical phase separation, and compounds with higher surface energy tend to be preferentially cured on the substrate surface.^{22,42,43} In the mixed ink system, there is a more favourable enthalpy interaction between PMMA and $\mathrm{SiO_{2,}}^{42}$ thus PMMA will preferentially deposit on the $SiO₂$ substrate, while the more hydrophobic C₆-DPA small

Fig. 2 (a–d) AFM images of the ink-printed C6-DPA film based on 4 : 1, 3 : 1, 2 : 1 and 1 : 1 C6-DPA/PMMA ratios. (e) OM and (f and g) POM images of the inkjet-printed crystalline film based on a 2 : 1 C6-DPA/PMMA ratio. The crossed arrows indicate the orientation of crossed polarizers. (h) Cross-sectional SEM image of a blend film with a 2:1 mix ratio.

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molecules will crystallize at the interface of air and the film, which is confirmed in the cross-sectional scanning electron microscope (SEM) image (Fig. 2h and Fig. S4, ESI†). When the proportion of PMMA increases, the small molecule OSCs cannot be separated from the polymer, instead they form dispersed crystal domains. This deteriorating degree of vertical phase separation can be reflected from the film roughness increase of the corresponding AFM images. This conclusion was confirmed by X-ray diffraction (XRD) measurements, as shown in Fig. S5 (ESI†). The diffraction peaks at $2\theta = 2.7^{\circ}$ of the films with other different blending ratios are weak, while the diffraction peaks of the films using C_6 -DPA/PMMA $(2:1)$ are sharper and stronger, indicating that the C_6 -DPA films have higher crystallinity. Furthermore, the diffraction peak intensities of the films are positively correlated with the molecular weight of the PMMA used, which is consistent with previous reports.⁴⁴ Fig. S6 (ESI⁺) shows the optical microscopy (OM) images of an inkjet-printed droplet array of the blend ink, and the diameter of each droplet is about 50–60 μ m with the optimal printing spacing *D* of 1/2– 2/3 of the diameter of each droplet. When the spacing of droplets is set to 25 μ m, a printed line with better shape is obtained. Furthermore, inkjet-printed C_6 -DPA films can also be fabricated (Fig. 2e). The two halves of the film exhibited simultaneous extinction with a 45° rotation of the polarization angle (Fig. 2f and g), suggesting that specific regions of the pattern may be single-crystal domains. Therefore, the optimal state of the ink is TCB as the solvent, with an ink concentration of 4 mg mL^{-1} , and a C₆-DPA/PMMA mass ratio of 2:1. It is worth mentioning that although the ink can form thin films when the concentration of C₆-DPA is larger than 3 mg mL^{-1} , the solute will precipitate out after the ink is left at room temperature for several days. Materials Advances

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To study the electrical properties of inks at different blend ratios, the electrical characteristics of C_6 -DPA films with different blend proportions were studied by constructing OFETs with a bottom-gate top-contact configuration using inkjet printing. Compared with the Ag electrode, the work function of the Au electrode is more matched with the energy level of C6-DPA.27,30 However, the deposition of the gold electrode will cause more serious thermal damage to our thin film, so we chose the Ag electrode. 300 nm $SiO₂$ was used as the dielectric layer and 40 nm Ag was adopted as the source and drain electrodes by thermal evaporation. The source– drain electrodes were smaller than the pattern size (Fig. 3a), which allows the measurement of the local C_6 -DPA film properties to test the uniformity of the C_6 -DPA film and obtain the spatial information of the electrical properties.⁴⁵ Because the underlying polymer is thin enough, calculated field-effect mobilities in this work only consider the capacitance of the $SiO₂$ dielectric regardless of the capacitance of PMMA, which results in a slight underestimation of the mobilities for all OFETs in this work. Before the I–V measurement, the thin film was divided into individual areas by probe tips scratching along the electrodes to avoid the fringe effect. The field-effect mobility of OFETs at the saturation region was calculated from the transfer I–V curves.

We plotted the transfer *I*–*V* curves and extracted mobilities (Fig. 3b and Fig. S7, ESI†) of C_6 -DPA/PMMA blends at different

Fig. 3 (a) The schematic diagram of the device preparation process, the chemical structure of blend inks and the test structure of the OFETs. (b) Transfer characteristics measured for bottom-gate, top-contact transistors with different blend ratios of C_6 -DPA/PMMA (ink concentration is $4 \text{ mg} \text{ mL}^{-1}$). (c) Output characteristics of OFETs prepared when the blend ratio of C_6 -DPA/PMMA is 2:1. (d) Comparison of mobility of OFETs based on C₆-DPA. (e) An OM image of the printed 4 \times 4 C₆-DPA thin film transistor array. (f) The distribution and (g) histogram of saturation mobility of 16 OFETs from the corresponding 4×4 array.

blend ratios (ink concentration = 4 mg mL^{-1}) to find the optimal value, where the average mobility was obtained based on 16 OFET measurements for each condition. The plot showed that the highest hole mobility was achieved when the blend ratio of C_6 -DPA/PMMA was equal to 2:1. The device performance obviously decreased when the blend ratio was less than 2 : 1, which may be because the amount of C_6 -DPA cannot completely cover the whole film and due to the appearance of dendrites and cracks in the C_6 -DPA film. The hole mobility also decreased when the blend ratio exceeded 2 : 1, in which small-molecules became stranded in the polymer due to the low concentration of the polymer, preventing the small-molecule OSCs from moving to the upper layer and deteriorating the effect of vertical phase separation. As a result, the highest OFET performance was achieved at 4 mg mL^{-1} with a 2:1 blend ratio (C₆-DPA = 2.65 mg mL⁻¹, PMMA = 1.35 mg mL⁻¹), the on/off ratio was greater than $10⁷$ and the maximum hole mobility was approximately 2.01 cm² V⁻¹ s⁻¹ in the saturation regime, outperforming the vast majority of C_6 -DPA-based single-crystal transistors (Fig. 3d). Then we selected a 4×4 transistor array (Fig. 3e), and counted its mobility distribution as shown in Fig. 3f and g. The mobility distribution is uniform, indicating that the uniformity between devices has been greatly improved, laying a solid foundation for its industrial application.

More importantly, the C_6 -DPA/PMMA binary blend ink remained transparent, uniform and stable in air for two months,

Fig. 4 (a) The electronic inks with different blend ratios of C_6 -DPA/ PMMA. (b) Transfer curves of OFETs based on electronic inks stored for different times.

as shown in Fig. 4a. Encouragingly, the performance of devices fabricated based on the ink stored for two months did not degrade significantly, indicating good air stability of the blend ink.

Conclusions

In conclusion, we prepared a functional C_6 -DPA/PMMA binary blend ink with high environmental stability and good performance. By introducing the insulating polymers and careful control of the vertical phase separation of the C_6 -DPA/PMMA binary blend ink, the crystallization of the C_6 -DPA film and device-to-device uniformity were improved distinctly. Through the analysis and characterization of inks with different conditions, we obtained the best ink preparation conditions, and the stability of the ink was guaranteed. Finally, we prepared highly stable and high-performance OFET devices through inkjet printing technology. This provides research guidance and the direction for the functionalization and commercialization of organic semiconductor inks. Paper Maccess Article 2022. **Computer Article is licensed on 22** November 2022. The state of the state o

Conflicts of interest

There are no conflicts to declare.

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